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# TRANSISTORS, LOW POWER, PNP

# BASED ON TYPE 2N2894 and 2N2894A

ESCC Detail Specification No. 5202/004

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### **DOCUMENTATION CHANGE NOTICE**

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442, 455	Specification up issued to incorporate editorial and technical changes per DCR.



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#### 1. <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

#### 1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

#### 1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

#### 1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

# 1.4.1 <u>The ESCC Component Number</u> The ESCC Component Number shall be constituted as follows:

Example: 520200401

- Detail Specification Reference: 5202004
- Component Type Variant Number: 01 (as required)

#### 1.4.2 <u>Component Type Variants</u>

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Lead/Terminal Material and/or Finish	Weight max g
01	2N2894	TO-18	D2	0.4
02	2N2894	TO-18	D2	0.4
03	2N2894	TO-18	D3 or D4	0.4
04	2N2894	TO-18	D3 or D4	0.4
05	2N2894	TO-18	D7	0.4
06	2N2894	CCP	2	0.06
07	2N2894	CCP	4	0.06

The lead/terminal material and/or finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.



#### 1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Collector-Base Voltage	V <sub>CBO</sub>	-12	V	Over entire
Collector-Emitter Voltage	V <sub>CEO</sub>	-12	V	operating temperature
Emitter-Base Voltage	V <sub>EBO</sub>	-4	V	range
Collector Current	۱ <sub>C</sub>	-200	mA	Continuous
Power Dissipation For TO-18 and CCP	P <sub>tot1</sub>	0.36	w	At T <sub>amb</sub> ≤ +25°C Note 1
For CCP	P <sub>tot2</sub>	0.58 (Note 2)	W	
For TO-18	P <sub>tot3</sub>	1.2	W	At T <sub>case</sub> ≤ +25 <sup>o</sup> C Note 1
Operating Temperature Range	T <sub>op</sub>	-65 to +200	°C	Note 3
Storage Temperature Range	T <sub>stg</sub>	-65 to +200	°C	Note 3
Soldering Temperature For TO-18 For CCP	T <sub>sol</sub>	+260 +245	°C	Note 4 Note 5

#### NOTES:

- 1. For  $T_{amb}$  or  $T_{case} > +25^{\circ}C$ , derate linearly to 0W at +200°C.
- 2. When mounted on a 15 x 15 x 0.6mm ceramic substrate.
- 3. For Variants with tin-lead plating or hot solder dip lead finish all testing, and any handling, performed at  $T_{amb} > +125^{\circ}C$  shall be carried out in a 100% inert atmosphere.
- 4. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 5. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.



#### 1.6 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

#### 1.6.1 Metal Can Package (TO-18) - 3 lead





Symbols	Dimensio	ons mm	Notes
Symbols	Min	Max	NOICS
A	4.32	5.33	
Øb	0.406	0.533	2, 3
Øb2	0.406	0.483	2, 3
ØD	5.31	5.84	
ØD1	4.52	4.95	
е	2.54	4	
e1	1.27	BSC	4
F	-	0.762	
j	0.914	1.17	
k	0.711	1.22	5
L	12.7	-	2
L1	-	1.27	3
L2	6.35	-	3
а	45° BSC		1, 4, 6

#### NOTES:

- 1. Terminal identification is specified by reference to the tab position where lead 1 = emitter, lead 2 = base, lead 3 = collector.
- 2. Applies to all leads.
- 3. Øb2 applies between L1 and L2. Øb applies between L2 and 12.7mm from the seating plane. Diameter is uncontrolled within L1 and beyond 12.7mm from the seating plane.
- 4. Leads having maximum diameter 0.483mm measured in the gauging plane 1.37(+0.025,-0)mm



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below the seating plane of the device shall be within 0.178mm of their true position relative to a maximum-width-tab.

- 5. Measured from the maximum diameter of the actual device.
- 6. Tab centreline.

#### 1.6.2 Chip Carrier Package (CCP) - 3 terminal



Symbols	Dimensio	ons mm	Notes
Symbols	Min	Max	110165
A	1.15	1.5	
С	0.45	0.56	2
D	0.6	0.91	2
E	0.91	1.12	
F	1.9	2.15	
G	2.9	3.25	
I	2.4	2.85	
L	0.4	0.6	2
М	2.4	2.65	
N1	0.855	1.055	
N2	1.8	2	
r	0.3 TYI	PICAL	1

#### NOTES:

- 1. Terminal identification is specified by reference to the corner notch position where terminal 1 = emitter, terminal 2 = base, terminal 3 = collector.
- 2. Applies to all terminals.



#### 1.7 <u>FUNCTIONAL DIAGRAM</u>



#### NOTES:

- 1. For TO-18, the collector is internally connected to the case.
- 2. For CCP, the lid is not connected to any terminal.

#### 1.8 <u>MATERIALS AND FINISHES</u>

Materials and finishes shall be as follows:

a) Case

For the metal can package the case shall be hermetically sealed and have a metal body with hard glass seals.

For the chip carrier package the case shall be hermetically sealed and have a ceramic body with a Kovar lid.

b) Leads/Terminals As specified in Component Type Variants.

#### 2. <u>REQUIREMENTS</u>

#### 2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 Deviations from the Generic Specification None.



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#### 2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number.
- (c) Traceability information.

#### 2.3 <u>TERMINAL STRENGTH</u>

The test conditions for terminal strength, tested as specified in the ESCC Generic Specification, shall be as follows:

For TO-18, Test Condition: E, lead fatigue.

- 2.4 <u>ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES</u> Electrical measurements shall be performed at room, high and low temperatures.
- 2.4.1 Room Temperature Electrical Measurements The measurements shall be performed at  $T_{amb}$ =+22 ±3°C.



Characteristics	Symbols	MIL-STD-750	Test Conditions	Lir	nits	Units
		Test Method		Min	Max	
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	3011	I <sub>C</sub> = -10mA Note 1 Bias condition D	-12	-	V
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	3001	I <sub>C</sub> = -10μA Bias condition D	-12	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	3026	I <sub>E</sub> = -100μA Bias condition D	-4	-	V
Collector-Base Cut-off Current	I <sub>CBO</sub>	3036	V <sub>CB</sub> = -10V Bias condition D	-	-100	nA
Forward-Current Transfer Ratio	h <sub>FE1</sub>	3076	V <sub>CE</sub> =-300mV; I <sub>C</sub> =-10mA Note 1 2N2894 2N2894A	30	-	-
	h <sub>FE2</sub>	3076	V <sub>CE</sub> =-500mV; I <sub>C</sub> =-30mA Note 1 2N2894 2N2894A	40 40	150 120	-
	h <sub>FE3</sub>	3076	V <sub>CE</sub> =-1V; I <sub>C</sub> =-100mA Note 1 2N2894 2N2894A	25 30		-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)1</sub>	3071	I <sub>C</sub> =-10mA I <sub>B</sub> =-1mA Note 1 2N2894 2N2894A	-	-150	mV
	V <sub>CE(sat)2</sub>	3071	I <sub>C</sub> =-30mA I <sub>B</sub> =-3mA Note 1 2N2894 2N2894A	-	-200 -190	mV
	V <sub>CE(sat)3</sub>	3071	I <sub>C</sub> =-100mA I <sub>B</sub> =-10mA Note 1 2N2894 2N2894A	-	-500 -450	mV



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Characteristics			Lin	nits	Units	
		Test Method		Min	Max	
Base-Emitter Saturation Voltage	V <sub>BE(sat)1</sub>	3066	I <sub>C</sub> =-10mA I <sub>B</sub> =-1mA Note 1 Test condition A 2N2894 2N2894A	-780	-980 -	mV
	V <sub>BE(sat)2</sub>	3066	I <sub>C</sub> =-30mA I <sub>B</sub> =-3mA Note 1 Test condition A 2N2894 2N2894A	-0.85 -	-1.2 -1.15	V
Magnitude of Small-Signal Short-Circuit Forward-Current Transfer Ratio	lh <sub>fe</sub> l	3306	V <sub>CB</sub> =-30mA, V <sub>CE</sub> =-10V f=100MHz Note 2 2N2984 2N2894A	4 7	-	-
Output Capacitance	C <sub>obo</sub>	3236	V <sub>CB</sub> =-5V, I <sub>E</sub> =0A f=1MHz Note 2 2N2984 2N2894A	-	6 4.5	pF
Input Capacitance	C <sub>ibo</sub>	3240	V <sub>EB</sub> =-500mV I <sub>C</sub> =0A f=1MHz Note 2	-	6	pF
Turn-on Time	t <sub>on</sub>	-	V <sub>BB</sub> =3V, V <sub>IN</sub> =-7V, I <sub>C</sub> =-30mA I <sub>BL</sub> =1.5mA Notes 2, 3 2N2984 2N2894A		60 40	ns
Turn-off Time	t <sub>off</sub>	-	V <sub>BB</sub> =-4V, V <sub>IN</sub> =6V, I <sub>C</sub> =-30mA I <sub>B1</sub> =I <sub>B2</sub> =1.5mA Notes 2, 3 2N2984 2N2894A	-	90 60	ns

#### NOTES:

1. Pulse measurement: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%

2. For AC characteristics read and record measurements shall be performed on a sample of 32 components with 0 failures allowed. Alternatively a 100% inspection may be performed.

3.  $t_{on}$  shall be measured using the following test circuit. The input waveform shall be supplied by a pulse generator with the following characteristics:  $Z_{OUT} = 50\Omega$ ,  $t_r \le 2ns$ , Pulse Width = 200 ±10ns, Duty Cycle  $\le 2\%$ . The output waveform shall be monitored on an oscilloscope with the following



# $V_{BB}$ $(100\Omega)$ $(0.1\mu F)$ $(0.1\mu F)$ $(100\Omega)$ $(100\Omega)$

# characteristics: $Z_{IN} \geq 100 k \Omega,$ input capacitance $\leq 12 p F, \, t_r \leq 1 n s.$



#### VOLTAGE WAVEFORM FOR $t_{on}$



VOLTAGE WAVEFORM FOR t<sub>off</sub>





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#### 2.4.2 <u>High and Low Temperatures Electrical Measurements</u>

Characteristics		Test Conditions	Limits		Units	
		Test Method	Note 1	Min	Max	
Collector-Base Cut-off Current	I <sub>СВО</sub>	3036	T <sub>amb</sub> =+150 (+0 -5) <sup>o</sup> C V <sub>CB</sub> =-50V Bias condition D	-	-10	μΑ
Forward-Current Transfer Ratio 2	h <sub>FE2</sub>	3076	T <sub>amb</sub> =-55 (+5 -0) <sup>o</sup> C V <sub>CE</sub> =-500mV I <sub>C</sub> =-30mA Note 2	20	-	-

#### NOTES:

- 1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.
- 2. Pulsed measurement: Pulse Width  $\leq$ 300µs, duty Cycle  $\leq$ 2%.

#### 2.5 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$ =+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols		Units			
	Drift		Abso	olute		
		Value A	Min	Max		
Collector-Base Cut-off Current	I <sub>CBO</sub>	±20 or (1) ±100%	-	-10	nA	
Forward-Current Transfer Ratio 2 2N2894 2N2894A	h <sub>FE2</sub>	±15%	40 40	150 150	-	
Collector-Emitter Saturation Voltage 3 2N2894 2N2894A	V <sub>CE(sat)</sub>	±50 or (1) ±15%	-	-500 -450	mV	

#### NOTES:

1. Whichever is the greater referred to initial value.



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#### 2.6 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$ =+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Collector-Base Cut-off Current	I <sub>CBO</sub>	-	-100	nA
Forward-Current Transfer Ratio 2 2N2894 2N2894A	h <sub>FE2</sub>	40 40	150 150	-
Collector-Emitter Saturation Voltage 3 2N2894 2N2894A	V <sub>CE(sat)</sub>	-	-500 -450	mV

#### 2.7 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+150 (+0 -5)	°C
Collector-Base Voltage	V <sub>CB</sub>	12	V
Duration	t	72 minimum	Hours

#### 2.8 <u>POWER BURN-IN CONDITIONS</u>

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+20 to +50	°C
Power Dissipation	P <sub>tot</sub>	As per Maximum Ratings P <sub>tot1</sub> derated at the chosen T <sub>amb</sub>	W
Collector-Base Voltage	V <sub>CB</sub>	-10	V

#### 2.9 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.